

Q1.

$$I_o = \mu_{GS} \times \frac{W}{2L} (V_{GS} - V_{TH})^2$$

$$= 100 \times 10^{-6} \times \frac{10}{2} \cdot (V_{GS} - 0.5)^2 = 100 \times 10^{-6}$$

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\therefore $5 (V_{GS} - 0.5)^2 = 1$; $(V_{GS} - 0.5) = 0.2$

$V_{GS} - 0.5 = \sqrt{2} = \pm 0.447$

$$V_{GS} = 0.947 \quad (\text{acceptable})$$

$$V_{GS} = V_G - V_S = V_G + 5 = 0.947$$

$\therefore V_G = -4.05 \text{ V.}$

Since $I_{ref} = I_o$, MOS being identical

$$R = \frac{9.05}{100 \mu A} = \frac{V_{DD} - V_S}{R} = \frac{5 + 4.05}{R}$$

\leftarrow design value (Ans.)

Q2: $I_o = I_{REF} \frac{1}{1 + \frac{n+1}{\beta}}$ n not given
let $n = 1$

$$I_{REF} - I_o = I_{REF} \left[1 - \left(\frac{1}{1 + \frac{n+1}{\beta}} \right) \right]$$

$$= I_{REF} \left[\frac{\frac{1+n+1}{\beta} - 1}{1 + \frac{n+1}{\beta}} \right] = I_{REF} \cdot \frac{n+1}{\beta + n + 1}$$

$$\frac{I_{REF} - I_o}{I_{REF}} = \frac{n+1}{\beta + n + 1} \quad \text{This should be } < 5\%$$

Q2

$$S_0 \frac{n+1}{\beta + n+1} < 0.05 , \beta > \frac{(n+1)(1-0.05)}{0.05}$$

If $n=1$, $\frac{2}{\beta+2} < 0.05$ $\beta > \frac{0.05}{0.05} = 19(n+1) \approx 1.9$

$$0.05\beta + 0.1 > 2 ; 0.05\beta > 1.9$$

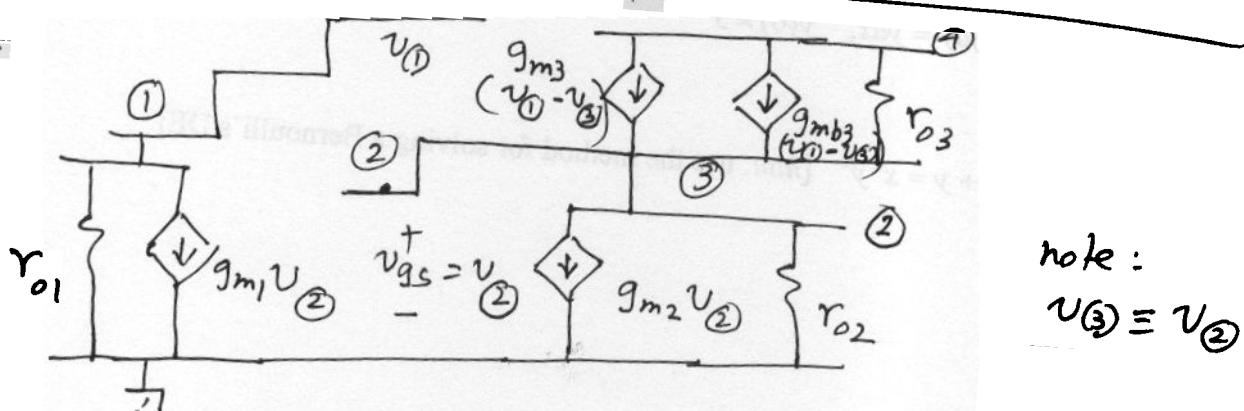
$$\beta > \frac{1.9}{0.05} = 38$$

If $n=2$, $\frac{3}{\beta+3} < 0.05$

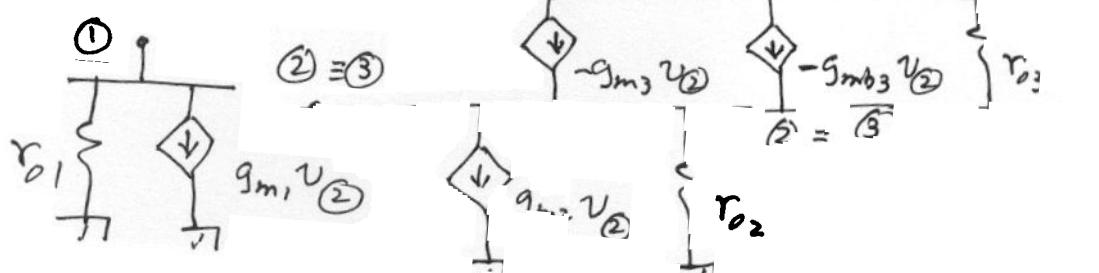
$$0.05\beta + 0.15 > 3 ; 0.05\beta > 2.85$$

$$\beta > 57$$

Q3:



$\therefore I_{REF}$ is DC no 'ac' current at node 1
So we can take $v_1 = 0$. for further simplification



Q4:

We need to use degenerating resistors in series with each emitter arm.

p3/4

With R_E as this resistance,

$$R_{in} = 2(\beta + 1)(R_E + r_e)$$

The voltage drop $2V_{be}$ is across $2(\beta + 1)r_e$ component

$$\text{So } 2(\beta + 1)r_e < 6 \text{ mV (rms)}$$

$$\text{or } (\beta + 1)r_e < 3 \text{ mV.}$$

For given problem, the total drop across $2(\beta + 1)(R_E + r_e)$ is 50 mV

$$\text{i.e. } (\beta + 1)(R_E + r_e) = 25 \text{ mV.}$$

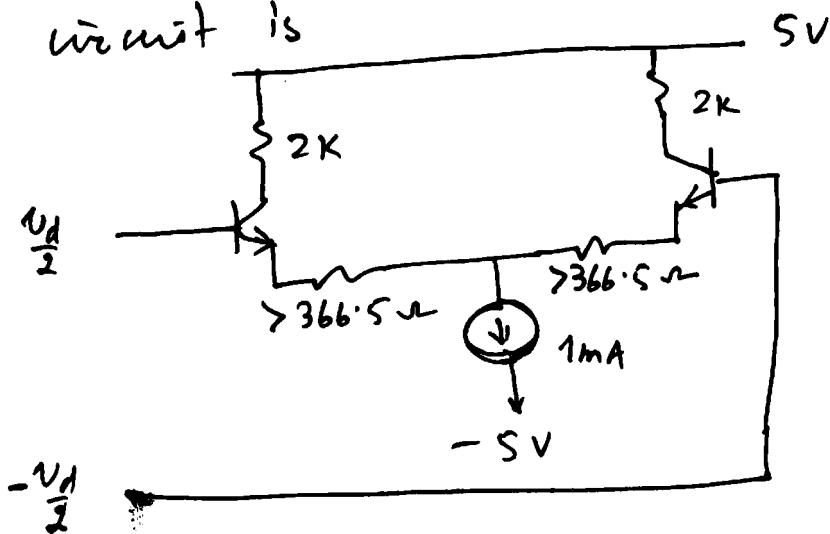
Taking the ratio. $\frac{R_E + r_e}{r_e} > \frac{25 \text{ mV}}{3 \text{ mV}} \rightarrow 8.33$

$$R_E > (8.33 - 1)r_e \rightarrow 7.33r_e$$

$$r_e \approx \frac{V_T}{I_E} = \frac{25 \text{ mV}}{0.5 \text{ mA}} = 50 \Omega$$

$$\text{So } R_E > 7.33 \times 50 \rightarrow 366.5 \Omega \rightarrow 390 \Omega \text{ a practical value}$$

Modified circuit is



Q.5: With active load, the differential gain is $-g_m \cdot (r_{o1} || r_{o2})$

p414

$$\text{Where } r_{o1} = \frac{V_{AN}}{I_{CN}}, \quad r_{o2} = \frac{V_{AT}}{I_Q}$$

$$\text{For the circuit } I_{CN} = I_{QP} \approx \frac{I_{EE}}{2} = 1 \text{ mA}$$

$$\text{So } r_{o1} = \frac{25}{1 \text{ mA}} = 25 \text{ k}\Omega \quad r_{o2} = \frac{50}{1 \text{ mA}} = 50 \text{ k}\Omega$$

$$g_m \approx \frac{f_E}{V_T} = \frac{1 \text{ mA}}{25 \text{ mV}} = 0.04 \text{ mho.} \quad \text{Note: } I_E \approx I_{CN} \\ \approx I_{QP}$$

$$\text{So voltage gain} = -0.04 \times 50 \text{ k}\Omega || 25 \text{ k}\Omega \\ = -0.04 \times 16.67 \text{ k}\Omega = -666.67 \text{ V/V.}$$

$$\text{Gain} \approx -666.67 \text{ V/V}$$

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